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SINGLE DIGIT LED DISPLAY (0.50 Inch)

LSD505/61-XX/RP20

DATA SHEET

DOC. NO : QW0905-LSD505/61-XX/RP20

REV. : A

DATE : 22 - Nov. - 2005



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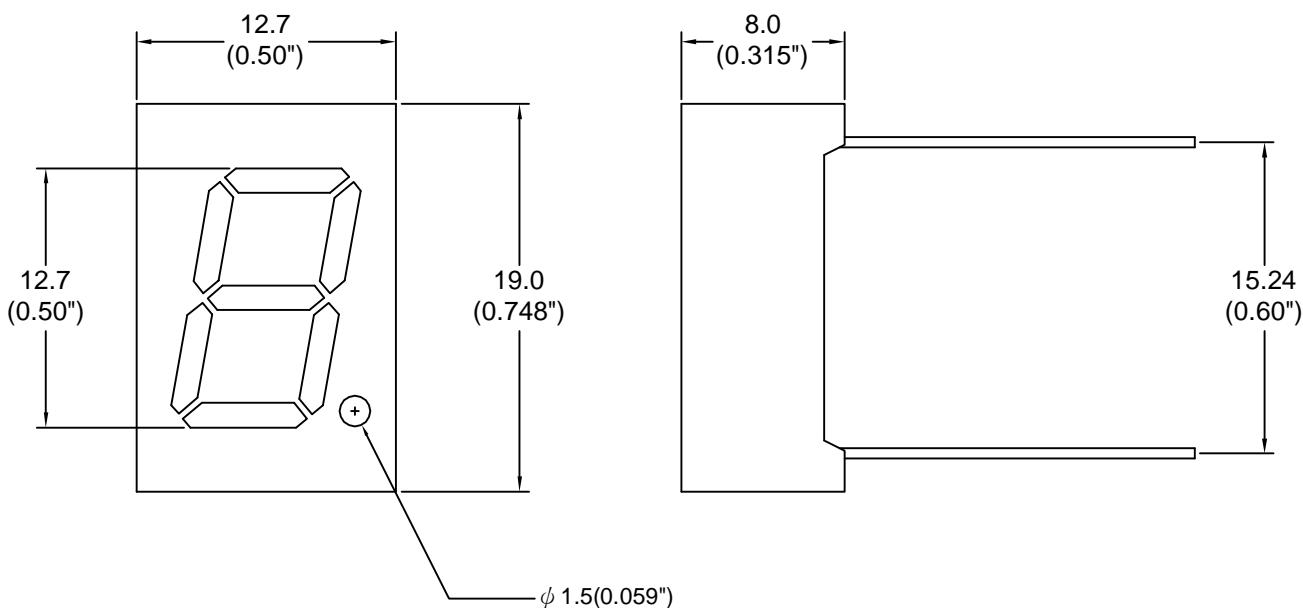
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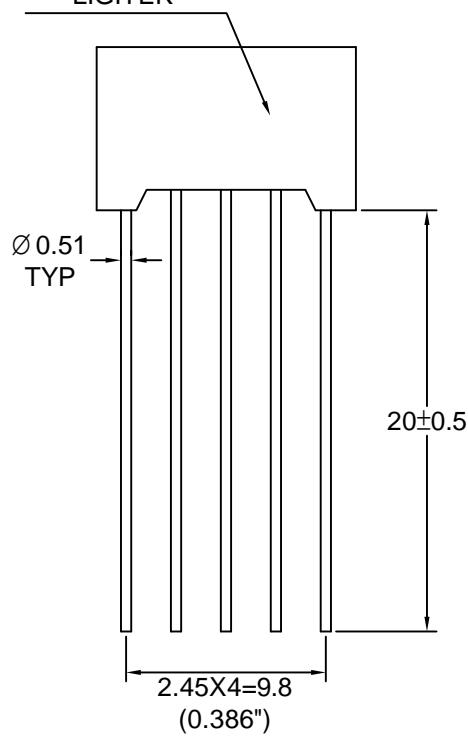
PART NO. LSD505/61-XX/RP20

Page 1/7

Package Dimensions



LSD505/61-XX/RP20
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PIN NO.1 →

Note : 1.All dimension are in millimeters and (Inch) tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
2.Specifications are subject to change without notice.



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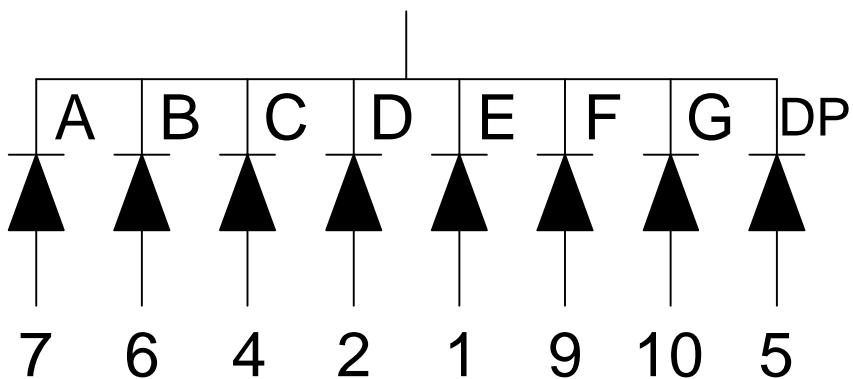
PART NO. LSD505/61-XX/RP20

Page 2/7

Internal Circuit Diagram

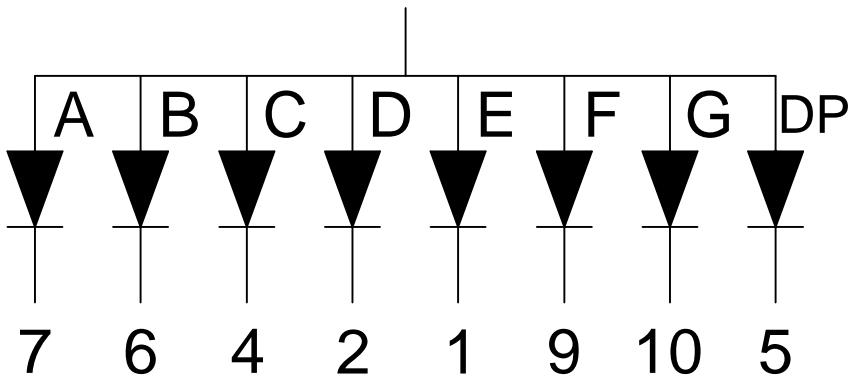
LSD5051-XX/RP20

3,8



LSD5061-XX/RP20

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PART NO. LSD505/61-XX/RP20

Page 3/7

Electrical Connection

PIN NO.	LSD5051-XX/RP20	PIN NO.	LSD5061-XX/RP20
1	Anode E	1	Cathode E
2	Anode D	2	Cathode D
3	Common Cathode	3	Common Anode
4	Anode C	4	Cathode C
5	Anode DP	5	Cathode DP
6	Anode B	6	Cathode B
7	Anode A	7	Cathode A
8	Common Cathode	8	Common Anode
9	Anode F	9	Cathode F
10	Anode G	10	Cathode G



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PART NO. LSD505/61-XX/RP20

Page 4/7

Absolute Maximum Ratings at Ta=25 °C

Parameter	Symbol	Ratings		UNIT
		H		
Forward Current Per Chip	I _F	15		mA
Peak Forward Current Per Chip (Duty 1/10,0.1ms Pulse Width)	I _{FP}	60		mA
Power Dissipation Per Chip	P _D	40		mW
Reverse Current Per Any Chip	I _r	10		μA
Operating Temperature	T _{opr}	-25 ~ +85		°C
Storage Temperature	T _{stg}	-25 ~ +85		°C
Solder Temperature 1/16 Inch Below Seating Plane For 3 Seconds At 260 °C				

Part Selection And Application Information(Ratings at 25°C)

PART NO	CHIP		common cathode or anode	λ P (nm)	△ λ (nm)	Electrical				IV-M
						Vf(v)		Iv(mcd)		
	Material	Emitted				Min.	Typ.	Max.	Min.	
LSD5051-XX/RP20	GaP	Red	Common Cathode	697	90	1.7	2.1	2.6	0.35	2:1
LSD5061-XX/RP20			Common Anode						0.5	

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.
 2. The luminous intensity data did not including ±15% testing tolerance.



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PART NO. LSD505/61-XX/RP20

Page 5/7

Test Condition For Each Parameter

Parameter	Symbol	Unit	Test Condition
Forward Voltage Per Chip	Vf	volt	If=20mA
Luminous Intensity Per Chip	Iv	mcd	If=10mA
Peak Wavelength	λ_P	nm	If=20mA
Spectral Line Half-Width	$\Delta\lambda$	nm	If=20mA
Reverse Current Any Chip	Ir	μA	Vr=5V
Luminous Intensity Matching Ratio	IV-M		



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PART NO. LSD505/61-XX/RP20

Page6/7

Typical Electro-Optical Characteristics Curve

H CHIP

Fig.1 Forward current vs. Forward Voltage

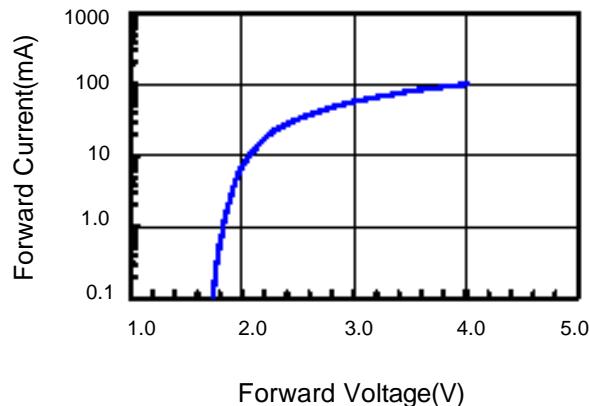


Fig.2 Relative Intensity vs. Forward Current

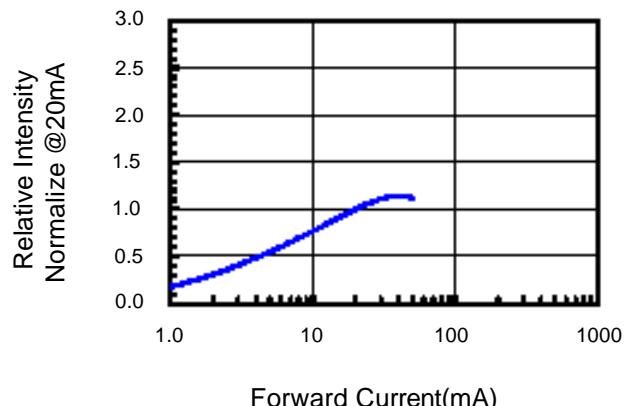


Fig.3 Forward Voltage vs. Temperature

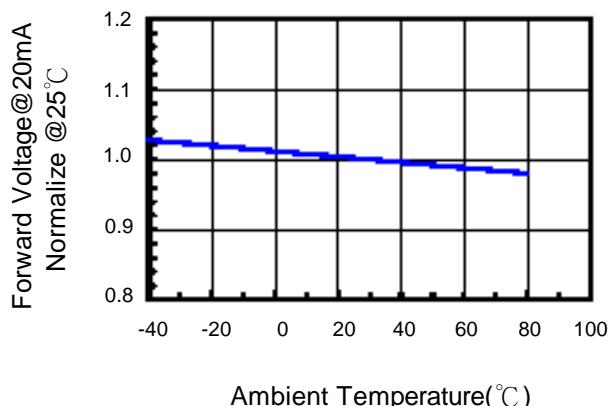


Fig.4 Relative Intensity vs. Temperature

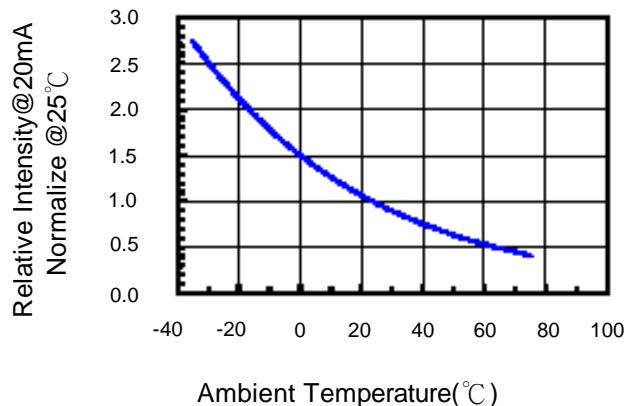
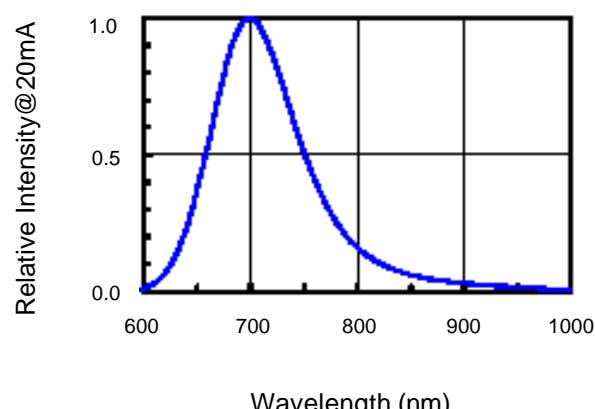


Fig.5 Relative Intensity vs. Wavelength



**Reliability Test:**

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=10mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 °C±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 °C±5°C 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 °C±5°C 2.RH=90%~95% 3.t=240hrs±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 °C±5°C &-40 °C±5°C (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 °C±5°C 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 °C±5°C 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2